

OSRAM SFH 464

Datasheet

Published by **ams-OSRAM AG**

Tobelbader Strasse 30, 8141 Premstaetten, Austria

Phone +43 3136 500-0

ams-osram.com

© All rights reserved



Metal Can® TO18

SFH 464 E7800

GaAlAs Light Emitting Diode (660 nm)



Applications

- Factory Automation

Features

- Package: clear epoxy
- ESD: 2 kV acc. to ANSI/ESDA/JEDEC JS-001 (HBM, Class 2)
- Radiation without IR in the visible red range
- Cathode is electrically connected to the case
- High reliability
- Same package as BP 103, SFH 4841
- DIN humidity category in acc. with DIN 40 040 GQG

Ordering Information

| Type | Radiant intensity ¹⁾²⁾ $I_F = 50 \text{ mA}; t_p = 20 \text{ ms}$ I_e | Radiant intensity ¹⁾ typ. I_e | Ordering Code |
|---------------|--|--|---------------|
| SFH 464 E7800 | 0.8 ... 2.6 mW/sr | 1.5 mW/sr | Q62702P1745 |

An aperture is used in front of the component for measurement of the radiant intensity and the half angle (diameter of the aperture: 1.1 mm; distance of aperture to case back side: 4.0 mm). This ensures that solely the radiation in axial direction emitting directly from the chip surface will be evaluated during measurement of the radiant intensity. Radiation reflected by the bottom plate (stray radiation) will not be evaluated. These reflections impair the projection of the chip surface by additional optics (e.g. long-range light reflection switches). In respect of the application of the component, these reflections are generally suppressed by apertures as well. This measuring procedure corresponding with the application provides more useful values. This aperture measurement is denoted by "E 7800" added to the type designation.

Maximum Ratings

 $T_A = 25\text{ °C}$

| Parameter | Symbol | | Values |
|--|----------------|--------------|-----------------|
| Operating temperature | T_{op} | min. max. | -40 °C 80 °C |
| Storage temperature | T_{stg} | min. max. | -40 °C 80 °C |
| Junction temperature | T_j | max. | 100 °C |
| Forward current | I_F | max. | 50 mA |
| Forward current pulsed $t_p \leq 10\ \mu\text{s}$; $D \leq 0.005$ | $I_{F\ pulse}$ | max. | 1 A |
| Reverse voltage ³⁾ | V_R | max. | 12 V |
| Power consumption | P_{tot} | max. | 140 mW |
| ESD withstand voltage acc. to ANSI/ESDA/JEDEC JS-001 (HBM, Class 2) | V_{ESD} | max. | 2 kV |

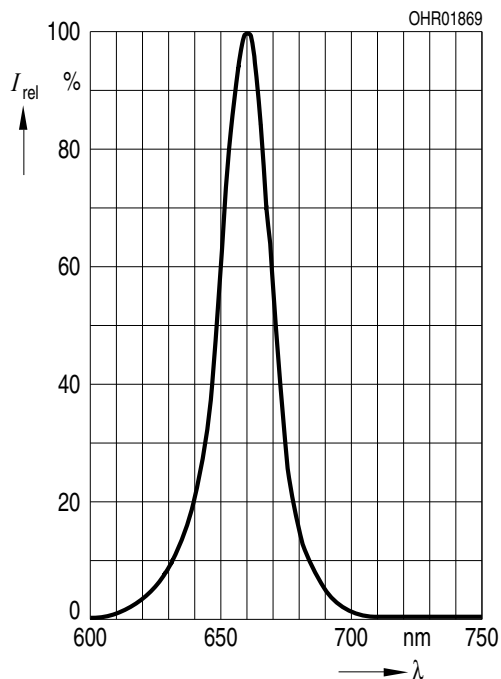
Characteristics

$I_F = 50 \text{ mA}$; $t_p = 20 \text{ ms}$; $T_A = 25 \text{ °C}$

| Parameter | Symbol | | Values |
|---|-------------------------|--------------|--|
| Peak wavelength | λ_{peak} | typ. | 660 nm |
| Spectral bandwidth at 50% $I_{\text{rel,max}}$ (FWHM) | $\Delta\lambda$ | typ. | 25 nm |
| Half angle | φ | typ. | 23 ° |
| Dimensions of active chip area | L x W | typ. | 0.325 x 0.325 mm x mm |
| Distance chip surface to lens top | H | min. max. | 0.3 mm 0.7 mm |
| Rise time (10% / 90%) $I_F = 50 \text{ mA}$; $R_L = 50 \text{ }\Omega$ | t_r | typ. | 100 ns |
| Fall time (10% / 90%) $I_F = 50 \text{ mA}$; $R_L = 50 \text{ }\Omega$ | t_f | typ. | 100 ns |
| Capacitance $V_R = 0 \text{ V}$; $f = 1 \text{ MHz}$ | C_0 | typ. | 30 pF |
| Forward voltage ⁴⁾ | V_F | typ. max. | 2.1 V 2.7 V |
| Reverse current ³⁾ $V_R = 3 \text{ V}$ | I_R | typ. max. | 0.01 μA 10 μA |
| Radiant intensity ¹⁾ $I_F = 1 \text{ A}$; $t_p = 20 \text{ }\mu\text{s}$ | I_e | typ. | 16 mW/sr |
| Total radiant flux ⁵⁾ | Φ_e | typ. | 11 mW |
| Temperature coefficient of voltage | TC_V | typ. | -3 mV / K |
| Temperature coefficient of brightness | TC_I | typ. | -0.4 % / K |
| Temperature coefficient of wavelength | TC_λ | typ. | 0.16 nm / K |
| Thermal resistance junction case real | R_{thJC} | max. | 160 K / W |
| Thermal resistance junction ambient real | R_{thJA} | max. | 450 K / W |

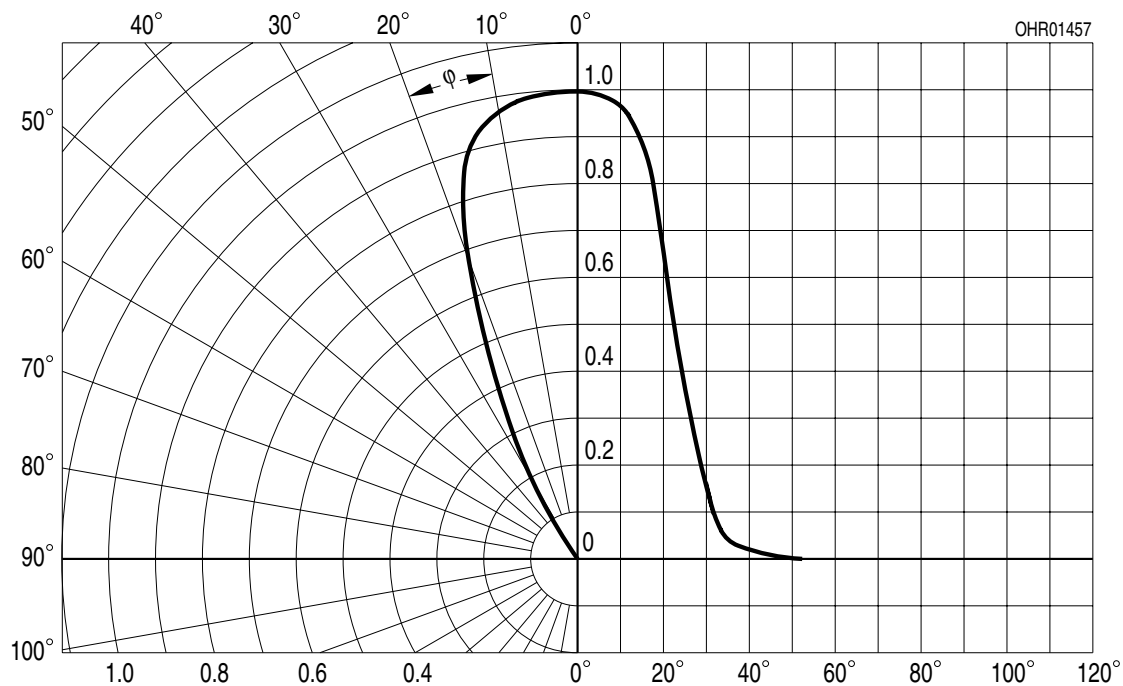
Relative Spectral Emission ^{6), 7)}

$$I_{e,rel} = f(\lambda); I_F = 50 \text{ mA}; t_p = 20 \text{ ms}$$



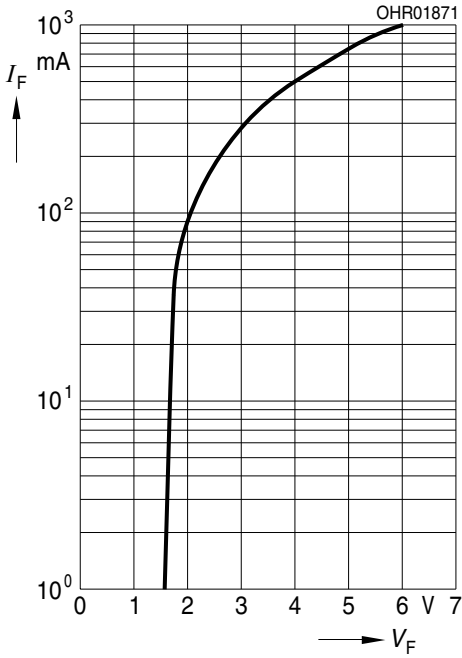
Radiation Characteristics ^{6), 7)}

$$I_{e,rel} = f(\varphi)$$



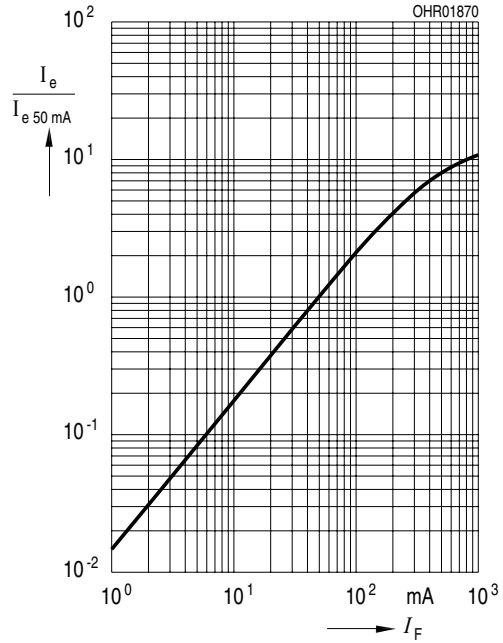
Forward current 6), 7)

$I_F = f(V_F)$; single pulse; $t_p = 100 \mu s$



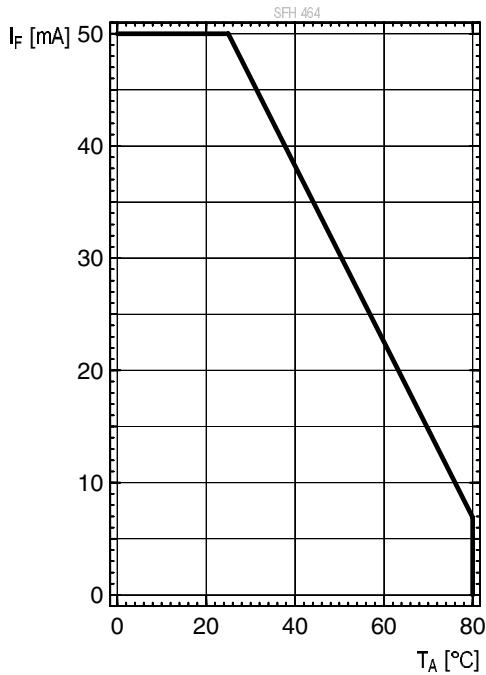
Relative Radiant Intensity 6), 7)

$I_e/I_e(50mA) = f(I_F)$; single pulse; $t_p = 20 \mu s$



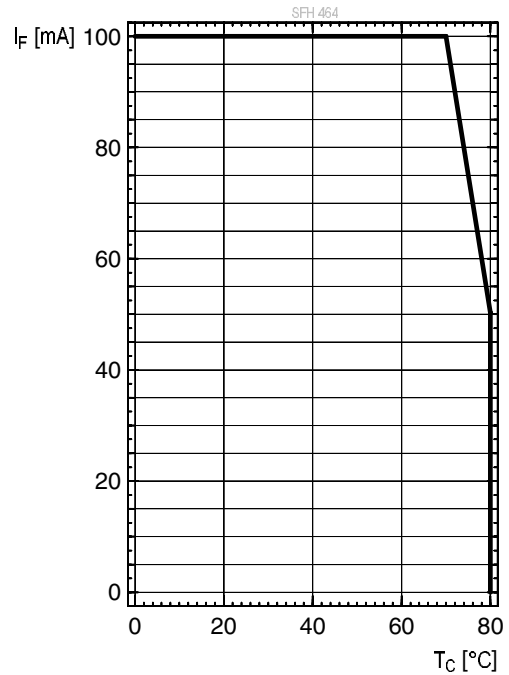
Max. Permissible Forward Current

$I_F = f(T_A)$; $R_{th_{ja}} = 450 \text{ K/W}$



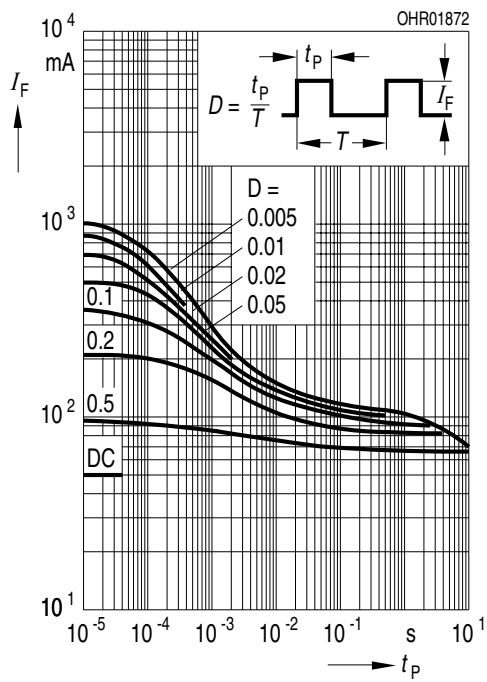
Max. Permissible Forward Current

$I_F = f(T_C)$; $R_{th_{jc}} = 160 \text{ K/W}$

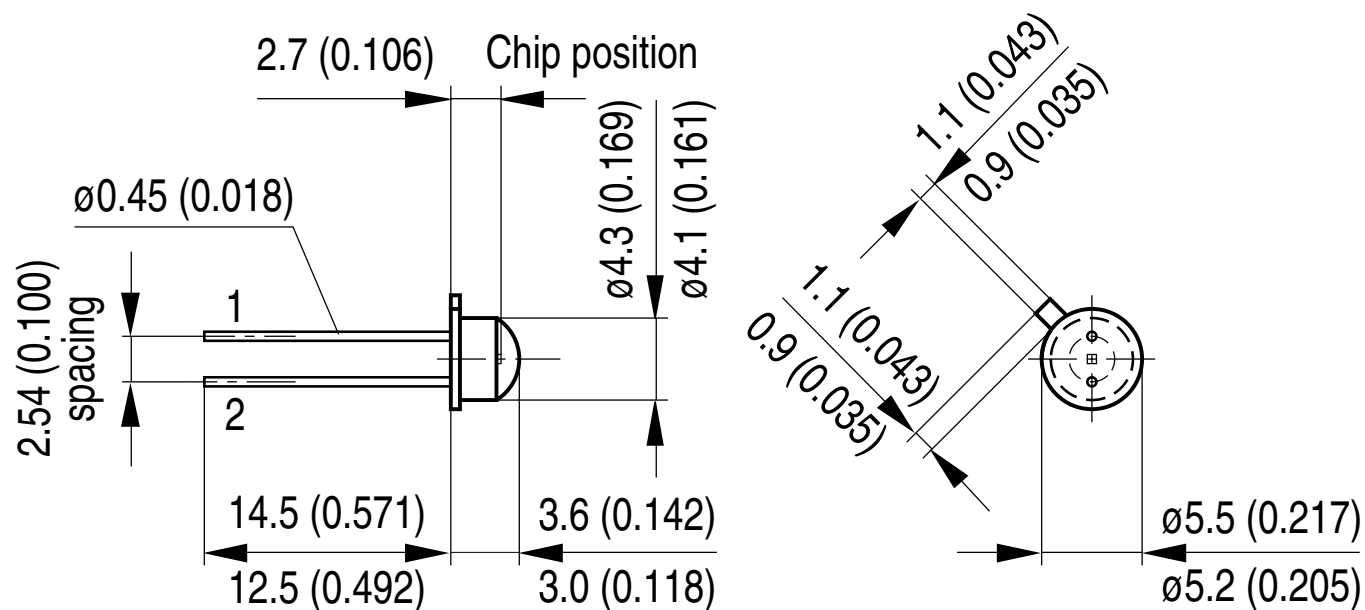


Permissible Pulse Handling Capability

$I_F = f(t_p)$; duty cycle $D =$ parameter; $T_A = 25^\circ\text{C}$



Dimensional Drawing ⁸⁾



GETY6625

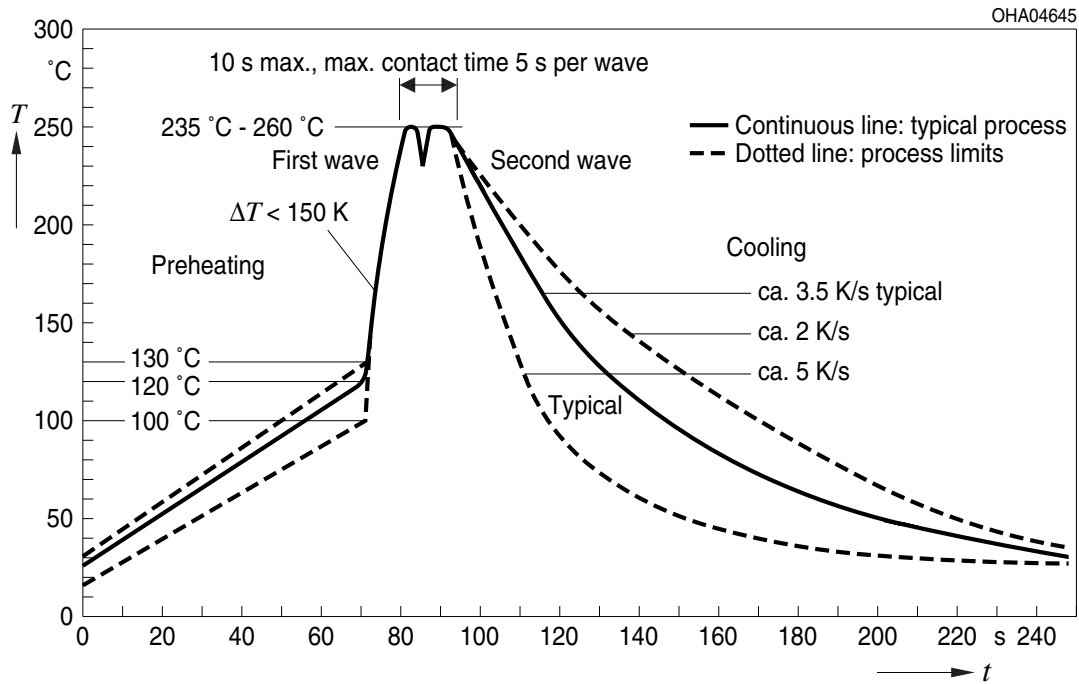
Further Information:

Approximate Weight: 180.0 mg

Package marking: Anode

TTW Soldering

IEC-61760-1 TTW



Notes

The evaluation of eye safety occurs according to the standard IEC 62471:2006 (photo biological safety of lamps and lamp systems). Within the risk grouping system of this IEC standard, the device specified in this data sheet fall into the class **exempt group (exposure time 10000 s)**. Under real circumstances (for exposure time, conditions of the eye pupils, observation distance), it is assumed that no endangerment to the eye exists from these devices. As a matter of principle, however, it should be mentioned that intense light sources have a high secondary exposure potential due to their blinding effect. When looking at bright light sources (e.g. headlights), temporary reduction in visual acuity and afterimages can occur, leading to irritation, annoyance, visual impairment, and even accidents, depending on the situation.

Subcomponents of this device contain, in addition to other substances, metal filled materials including silver. Metal filled materials can be affected by environments that contain traces of aggressive substances. Therefore, we recommend that customers minimize device exposure to aggressive substances during storage, production, and use. Devices that showed visible discoloration when tested using the described tests above did show no performance deviations within failure limits during the stated test duration. Respective failure limits are described in the IEC60810.

For further application related information please visit www.osram-os.com/appnotes

Disclaimer

Attention please!

The information describes the type of component and shall not be considered as assured characteristics. Terms of delivery and rights to change design reserved. Due to technical requirements components may contain dangerous substances.

For information on the types in question please contact our Sales Organization.

If printed or downloaded, please find the latest version on our website.

Packing

Please use the recycling operators known to you. We can also help you – get in touch with your nearest sales office. By agreement we will take packing material back, if it is sorted. You must bear the costs of transport. For packing material that is returned to us unsorted or which we are not obliged to accept, we shall have to invoice you for any costs incurred.

Product and functional safety devices/applications or medical devices/applications

Our components are not developed, constructed or tested for the application as safety relevant component or for the application in medical devices.

Our products are not qualified at module and system level for such application.

In case buyer – or customer supplied by buyer – considers using our components in product safety devices/ applications or medical devices/applications, buyer and/or customer has to inform our local sales partner immediately and we and buyer and /or customer will analyze and coordinate the customer-specific request between us and buyer and/or customer.

Glossary

- 1) **Radiant intensity:** Measured at a solid angle of $\Omega = 0.01$ sr
- 2) **Brightness:** The brightness values are measured with a tolerance of $\pm 11\%$.
- 3) **Reverse Operation:** This product is intended to be operated applying a forward current within the specified range. Applying any continuous reverse bias or forward bias below the voltage range of light emission shall be avoided because it may cause migration which can change the electro-optical characteristics or damage the LED.
- 4) **Forward Voltage:** The forward voltages are measured with a tolerance of ± 0.1 V.
- 5) **Total radiant flux:** Measured with integrating sphere.
- 6) **Typical Values:** Due to the special conditions of the manufacturing processes of semiconductor devices, the typical data or calculated correlations of technical parameters can only reflect statistical figures. These do not necessarily correspond to the actual parameters of each single product, which could differ from the typical data and calculated correlations or the typical characteristic line. If requested, e.g. because of technical improvements, these typ. data will be changed without any further notice.
- 7) **Testing temperature:** $T_A = 25^\circ\text{C}$ (unless otherwise specified)
- 8) **Tolerance of Measure:** Unless otherwise noted in drawing, tolerances are specified with ± 0.1 and dimensions are specified in mm.

Revision History

| Version | Date | Change |
|---------|------------|---|
| 1.4 | 2019-10-15 | Ordering Information Characteristics |
| 1.5 | 2022-06-22 | Ordering Information New Layout |
| 1.6 | 2022-09-05 | Applications Derating (Diagrams) |



EU RoHS and China RoHS compliant product

此产品符合欧盟 RoHS 指令的要求；
按照中国的相关法规和标准，
不含有毒有害物质或元素。

Published by ams-OSRAM AG

Tobelbader Strasse 30, 8141 Premstaetten, Austria

Phone +43 3136 500-0

ams-osram.com

© All rights reserved

am 

OSRAM